

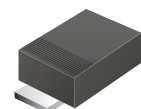
CDBMTS120-HF Thru. CDBMTS1200-HF

Reverse Voltage: 20 to 200 Volts

Forward Current: 1.0 Amp

RoHS Device

Halogen Free

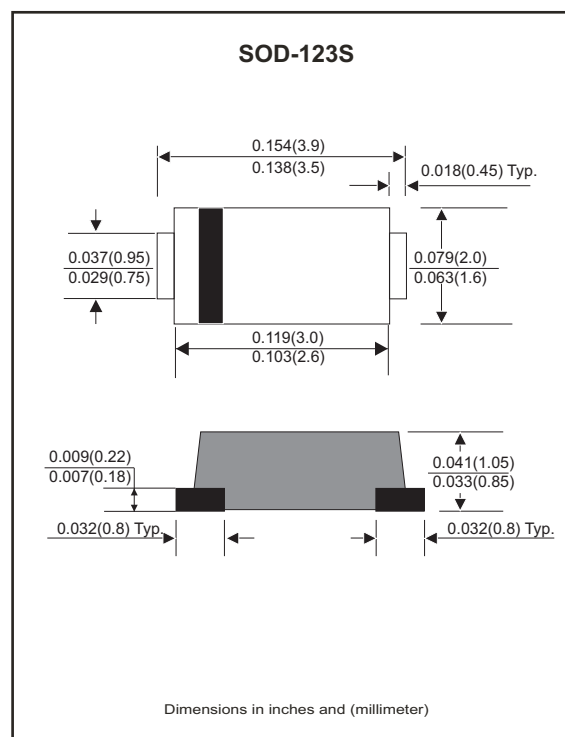


Features

- Excellent power dissipation offers better reverse leakage current and thermal resistance.
- Low profile package is 40% thinner than standards SOD-123.
- Low power loss,high efficiency.
- High current capability,low forward voltage drop.
- High surge capability.
- Guarding for overvoltage protection.
- Ultra high-speed switching.
- Silicon epitaxial planar chip,metal silicon junction.
- Lead-free part meets environmental standards of MIL-STD-19500/228

Mechanical data

- Epoxy: UL94-V0 rated flame retardant.
- Case: Molded plastic, SOD-123S/MINI SMA
- Terminals: Solderable per MIL-STD-750, Method 2026.
- Polarity: Indicated by cathode band.
- Mounting Position: any
- Weight: 0.0155 grams approx.



Electrical Characteristics (at T_A=25°C unless otherwise noted)

Parameter	Symbol	CDBMTS 120-HF	CDBMTS 130-HF	CDBMTS 140-HF	CDBMTS 150-HF	CDBMTS 160-HF	CDBMTS 180-HF	CDBMTS 1100-HF	CDBMTS 1150-HF	CDBMTS 1200-HF	Unit
Repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	80	100	150	200	V
Continuous reverse voltage	V _R	20	30	40	50	60	80	100	105	140	V
RMS voltage	V _{RMS}	14	21	28	35	42	56	70	150	200	V
Maximum Forward rectified current	I _O	1.0									A
Maximum forward voltage @ I _F =1.0A	V _F	0.50			0.70		0.85		0.92		V
Maximum forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC methode)		I _{FSM}	30								A
Maximum reverse Current (V _R =V _{RRM})	T _J =25°C	I _R	0.5								mA
	T _J =100°C		10								
Typical diode Junction capacitance (F=1MHz and applied 4V DC reverse voltage)		C _J	120								pF
Operating temperature		T _J	-55 to +125			-55 to +150					°C
Storage temperature range		T _{STG}	-65 to +175								°C

Rating and Characteristic Curves (CDBMTS120-HF Thru. CDBMTS1200-HF)

Fig.1- Typical Forward Current Derating Curve

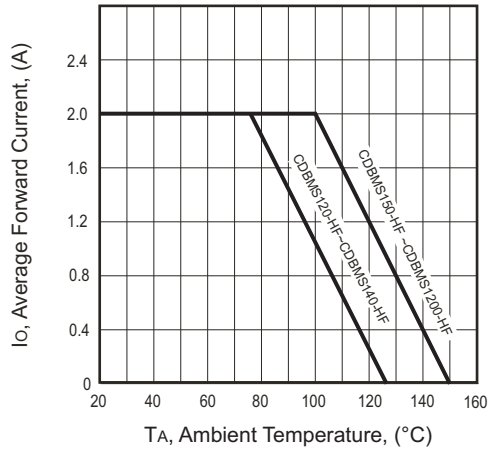


Fig.2 - Typical Forward Characteristics

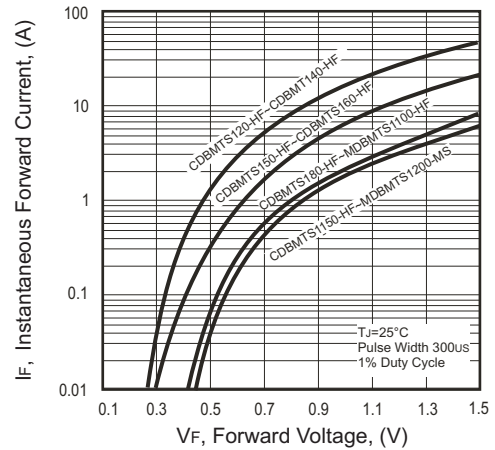


Fig.3 - Maximum Non-repetitive Forward Surge Current

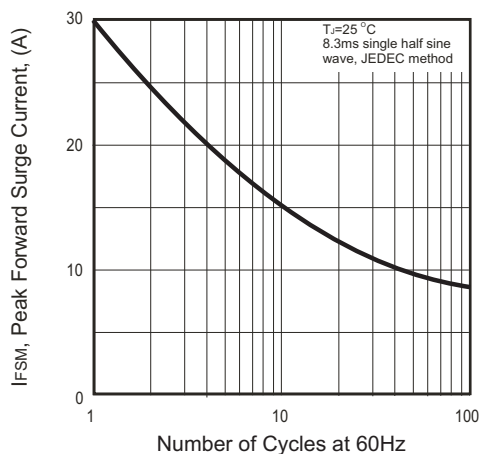


Fig.4 - Typical Junction Capacitance

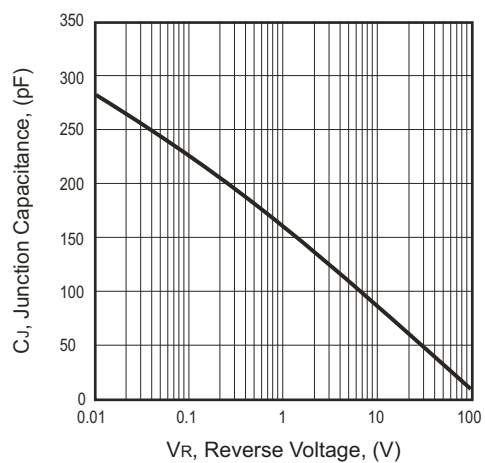
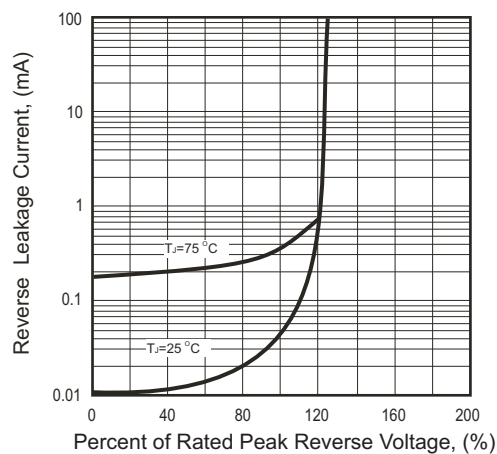
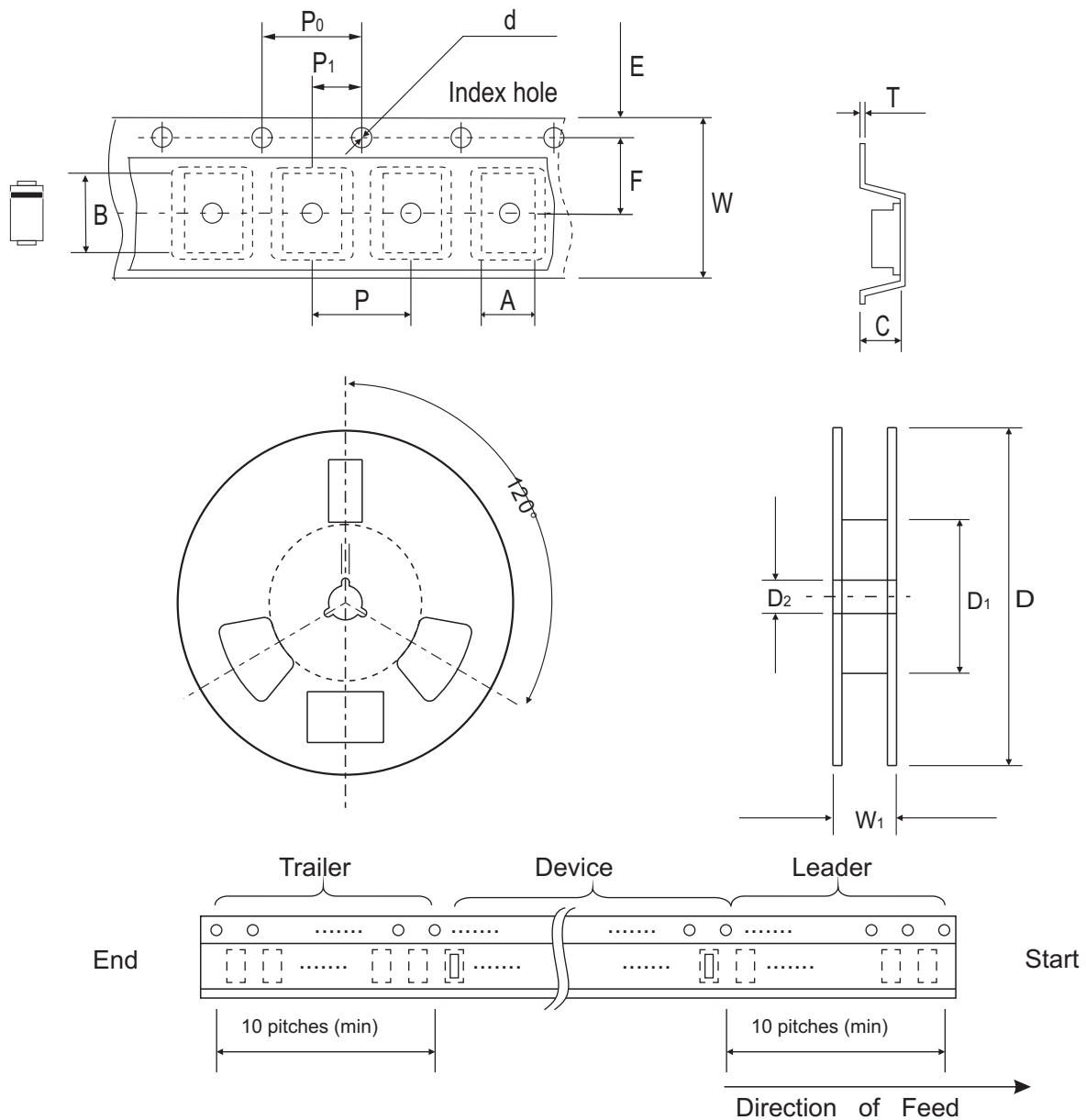


Fig.5 - Typical Reverse Characteristics



Reel Taping Specification



SOD-123S	SYMBOL	A	B	C	d	D	D1	D2
	(mm)	2.00 ± 0.10	3.85 ± 0.10	1.10 ± 0.10	1.50 ± 0.10	178 ± 2.00	62.0 MIN.	13.0 ± 0.50
	(inch)	0.079 ± 0.004	0.152 ± 0.004	0.043 ± 0.004	0.059 ± 0.004	7.00 ± 0.079	2.440 MIN.	0.512 ± 0.020

SOD-123S	SYMBOL	E	F	P	P0	P1	T	W	W1
	(mm)	1.75 ± 0.10	3.50 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.10	0.23 ± 0.10	8.00 ± 0.30	11.40 ± 1.0
	(inch)	0.069 ± 0.004	0.138 ± 0.004	0.157 ± 0.004	0.157 ± 0.004	0.079 ± 0.004	0.009 ± 0.004	0.315 ± 0.012	0.449 ± 0.039

Pinning information

Pin	Simplified outline	Symbol
PIN 1 Cathode PIN 2 Anode		

Marking Code

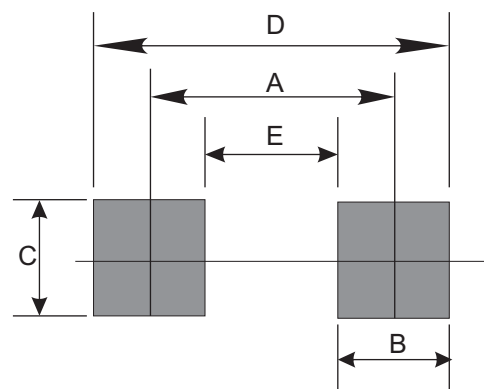
Part Number	Marking Code
CDBMTS120-HF	12
CDBMTS130-HF	13
CDBMTS140-HF	14
CDBMTS150-HF	15
CDBMTS160-HF	16
CDBMTS180-HF	18
CDBMTS1100-HF	10
CDBMTS1150-HF	115
CDBMTS1200-HF	120



xx / xxx = Product type marking code

Suggested PAD Layout

SIZE	SOD-123S	
	(mm)	(inch)
A	3.00	0.118
B	1.00	0.039
C	0.90	0.036
D	4.00	0.157
E	2.00	0.079



Standard Packaging

Case Type	REEL PACK	
	REEL (pcs)	Reel Size (inch)
SOD-123S	2,500	7

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

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[CDBMTS1200-HF](#) [CDBMTS140-HF](#) [CDBMTS1150-HF](#) [CDBMTS160-HF](#) [CDBMTS1100-HF](#)